

Technical Data Sheet 5mm Phototransistor T-1

DT2



Features

- Fast response time
- High photo sensitivity
- Pb free
- This product itself will remain within RoHS compliant version.

Descriptions

• PT334-6B is a high speed and high sensitive NPN silicon NPN epitaxial planar phototransistor molded in a standard 5 mm package. Due to is black epoxy the device is sensitive to visible and near Infrared radiation.

Applications

- Infrared applied system
- Camera
- Cockroach catcher

Device Selection Guide

LED Part No.	Chip	Lens Color	
LED I alt No.	Material		
PT334-6B	Silicon	Black	

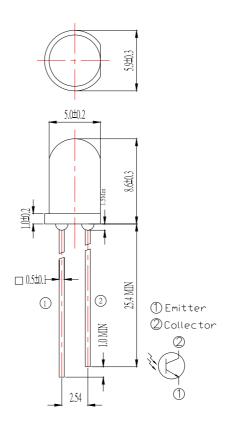
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Package Dimensions



Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.25mm

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector-Voltage	V_{ECO}	5	V
Collector Current	I_{C}	20	mA
Operating Temperature	Topr	-25 ~ +85°C	$^{\circ}\!\mathbb{C}$
Storage Temperature	Tstg	-40 ~ +85°C	$^{\circ}$
Lead Soldering Temperature	Tsol	260	$^{\circ}\!\mathbb{C}$
Power Dissipation at (or			
below)	Pc	75	mW
25°C Free Air Temperature			

Notes: *1:Soldering time ≤ 5 seconds.

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Electro-Optical Characteristics (Ta=25 $^{\circ}$ C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Collector – Emitter	BV _{CEO}	$I_{C}=100 \mu A$ Ee=0mW/cm ²	30			V
Breakdown Voltage		LC=OIII W/CIII				
Emitter-Collector	BV _{ECO}	$I_E=100 \mu A$ $Ee=0 \text{mW/cm}^2$	5			V
Breakdown Voltage	2 · ECO	Ee=0mw/cm	3			
Collector-Emitter	V _{CE)(sat)}	$I_{C}=2mA$ Ee=1mW/cm ²			0.4	V
Saturation Voltage	V CE)(sat)	Ee=1mw/cm				
Rise Time	t_r	$V_{CE}=5V$		15		
Fall Time	$t_{\rm f}$	$I_{C}=1$ mA RL= 1000Ω		15		μ S
Collector Dark Current	I_{CEO}	Ee=0mW/cm ² V _{CE} =20V			100	nA
On State Collector Current	I _{C(on)}	Ee=1mW/cm ² V _{CE} =5V	0.7	2.0		mA
Wavelength of	λр			940		nm
Peak Sensitivity	/ P) 1 0		11111
Rang of Spectral Bandwidth	λ 0.5			840-1200		nm

Rankings

Parameter	Symbol	Min	Max	Unit	Test Condition
G		0.70	1.90		
Н		1.14	2.60		Vce=5V
Ј	Ic(ON)	1.77	3.61	mA	Ee=1mW/cm ²
K		2.67	5.07		
L		4.18	7.07		

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Typical Electro-Optical Characteristics Curves

Fig.1Collector Power Dissipation vs.
Ambient Temperature

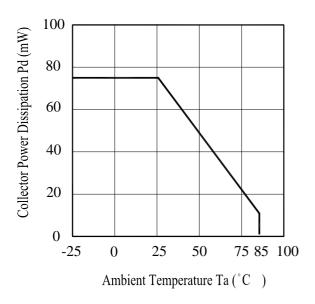


Fig.2 Spectral Sensitivity
T_a=25°C

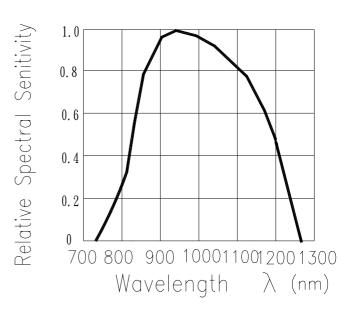


Fig.3 Relative Collector Current vs. Ambient Temperature

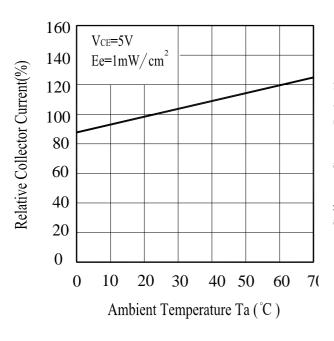
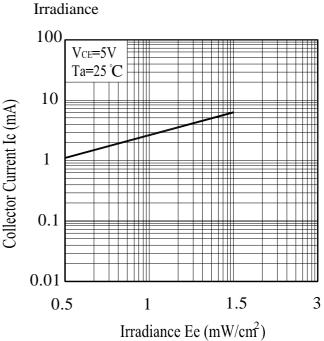


Fig.4 Collector Current vs.



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Typical Electro-Optical Characteristics Curves

Fig.5 Collector Dark Current vs.

Ambient Temperature

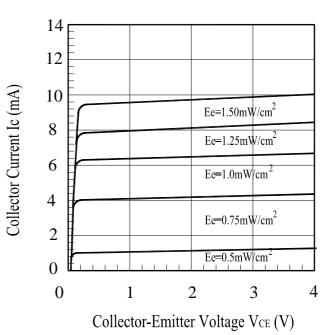
10⁻⁶
5
VCE=20V

OED 10⁻⁷
10⁻⁸
5
10⁻⁸
5
10⁻⁹
10⁻⁹
0
25
50
75
100

Ambient Temperature Ta (°C)

Fig.6 Collector Current vs.

Collector-Emitter Voltage



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Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditions	Test Hours/	Sample	Failure	Ac/Re
			Cycles	Sizes	Judgement	
					Criteria	
1	Solder Heat	TEMP. : 260°C±5°C	10secs	22pcs		0/1
2	Temperature Cycle	$H:+100^{\circ}C$ 15mins	300Cycles	22pcs		0/1
		5mins			$I_{C(ON)} \leq L \times 0.8$	
		L: -40°C				
3	Thermal Shock	H :+100°C ▲ 5mins	300Cycles	22pcs	L: the initial test	0/1
		▼ 10secs			value	
		L:- 10° C 5mins				
4	High Temperature	TEMP. ∶ +100°C	1000hrs	22pcs		0/1
	Storage					
5	Low Temperature	TEMP. : -40°C	1000hrs	22pcs		0/1
	Storage			_		
6	DC Operating Life	V _{CE} =5V	1000hrs	22pcs		0/1
7	High Temperature/	85°C / 85% R.H	1000hrs	22pcs		0/1
	High Humidity					

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Packing Quantity Specification

1.500PCS/1Bag, 6Bags/1Box

2.10Boxes/1Carton

Label Form Specification



CPN: Customer's Production Number

P/N: Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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